

Light Avenue Premium Edition LED series is designed for high performance consumer applications. Remarkable light extraction is reached by a particular top emitting design with vertical chip structure. As this die can be driven at very high currents compared to the chip size, an outstanding cost vs. performance ratio can be obtained.



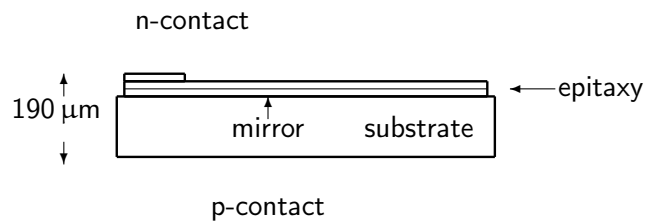
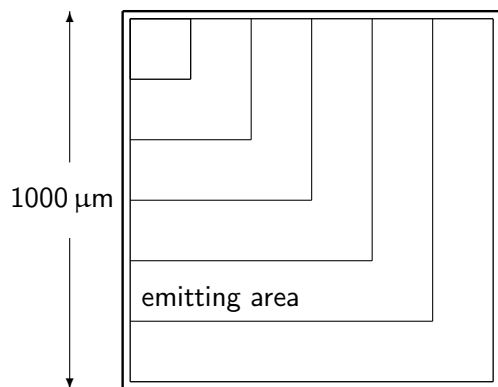
Features

- Highest brightness InGaN chip
- Top emitting device
- Lambertian radiation
- Optimized for SMT applications
- Grouping: luminous intensity, wavelength
- Chip with 5 contact rings

Applications

- Solid state lighting
- LCD backlighting
- Lamps
- Displays
- Light indicators

Delineation



Mechanical characteristics

DESCRIPTION	MINIMUM	TYPICAL ¹	MAXIMUM
Chip size (μm)	950	1000	1050
Chip height (μm)	170	190	210
Bond pad diameter (μm)	160	180	200
Top contact	Cathode (n), gold		
Bottom contact	Anode (p), AuSn		
Die attach	Soldering		

Electro-optical characteristics ($T_A = 25^\circ\text{C}$)²

PARAMETER	SYMBOL	CONDITION	MIN.	TYP. ¹	MAX.	UNIT
Forward voltage	V_F	$I_F = 350\text{ mA}$	2.70		3.80	V
Reverse voltage	V_R	$I_R = 10\ \mu\text{A}$	5.0			V
Dominant wavelength	λ_{dom}	$I_F = 350\text{ mA}$	515		537.5	nm
Luminous intensity	I_v	$I_F = 350\text{ mA}$	8000			mcd

Maximum ratings ($T_A = 25^\circ\text{C}$)³

PARAMETER	SYMBOL	VALUE	UNIT
Operating temperature range	T_{op}	-40...+85	°C
Forward current	I_F	350	mA
LED junction temperature	T_j	125	°C

Binning ($I_F = 350\text{ mA}$)⁴

		WAVELENGTH (NM)							
		515-520	517.5-522.5	520-525	522.5-527.5	525-530	527.5-532.5	530-535	532.5-537.5
Luminous intensity (mcd)	> 8000	A46	AM46	B46	BM46	C46	CM46	D46	DM46
	> 10000	A47	AM47	B47	BM47	C47	CM47	D47	DM47
	> 12500	A48	AM48	B48	BM48	C48	CM48	D48	DM48
	> 16000	A49	AM49	B49	BM49	C49	CM49	D49	DM49
	> 20000	A50	AM50	B50	BM50	C50	CM50	D50	DM50

Notes:

- The usage of LEDs in life-support devices or systems has to be expressly and written authorized by the supplier!
- Dice are sensitive to ESD.
- Dice are shipped on blue foil with or without frame and have therefore to be stored between 15 and 30°C and below 60% relative humidity.
- Lead free product - RoHS compliant.
- The information in this document is subject to change without notice and describes the die generally. It shall not be considered as assured characteristics or detailed specification.

- The quality level of the final visual inspection shall comply to an AQL of 1.0 (according to MIL-STD-105E, level II), if the customer performs an incoming visual inspection of a shipment.
- All chips are checked according to the "Failure Catalog of Light Avenue dice" dated 2009-11-14. If this document is not familiar to you, please request it at your next sales office.

¹Typical (Typ) data are defined as long-term production mean values. These values are not specified and only given for information.

²Measurements are done with an accuracy of $\pm 15\%$. Correlation to customer's equipment and products is required.

³Maximum ratings are package dependent and may differ between packages. The forward current is not limited by the die but by the effect of the LED junction temperature on the package. If you need more information on pulsed operation, please contact your next sales office about possible driving conditions. If not otherwise specified the maximum pulse current may not exceed the maximum current in continuous mode.

⁴There may be more than one bin on one single foil. Single bins cannot be ordered.